

Abstract

The invention relates to a method for controlling the operating point of a transistor of a power amplifier for amplifying time division multiplex (access) TDM(A)-signals. Methods to compensate drifts of the operating point caused by temperature variations are in principle known in the art. However, the methods known in the art have the disadvantage that they are not precise enough during the operation of such power amplifiers, in particular when amplifying high-frequency TDM(A)-signals. In order to overcome said problem the invention proposes to carry out the controlling of the operating point during null power time slots of said TDM-signal.